

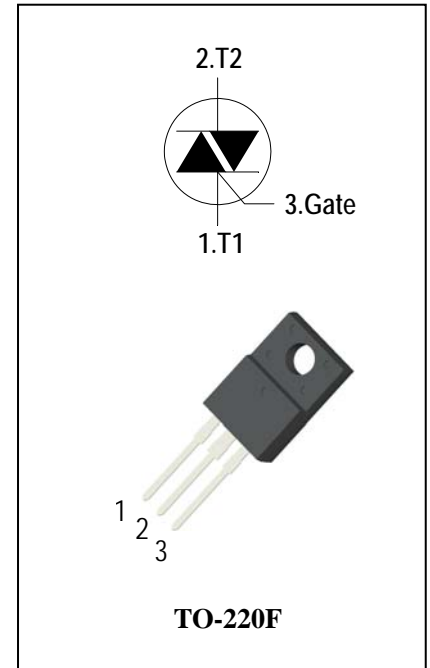
### 3 Quadrants High temperature Triacs

#### General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADT25CH triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners, Rectifier-fed DC inductive loads e.g. DC motors and solenoids , motor speed controllers. The heatsink can be reduced, compared to traditional triacs, according to the high performance at given junction temperatures.

#### Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (  $I_{T(RMS)} = 25A$  )
- ◆ High Commutation  $dv/dt$
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



#### Absolute Maximum Ratings

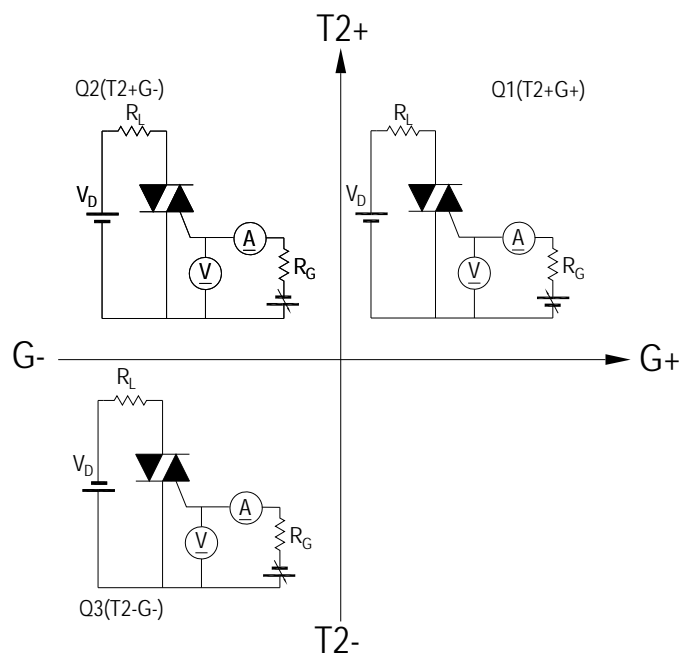
Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$ $V_{RRM}$	Repetitive Peak Off-State Voltage	$T_j = 25^{\circ}C$	ADT25CH60F	600	V
			ADT25CH80F	800	V
$I_{T(RMS)}$	R.M.S On-State Current	$T_C = 100^{\circ}C$		25	A
$I_{TSM}$	Surge On-State Current	$t_p=20ms(50Hz)/t_p=16.7ms(60Hz)$		250/260	A
$I^2t$	$I^2t$ for fusing	$t_p=10ms$		335	$A^2s$
$di/dt$	Critical rate of rise of on-state current	$F = 120\text{ Hz}$ $T_j = 150^{\circ}C$ $I_G = 2 \times I_{GT}$ , $tr \leq 100\text{ ns}$		55	$A/\mu s$
$I_{GM}$	Peak Gate Current	$t_p = 20\text{ }\mu s$ $T_j = 150^{\circ}C$		4	A
$P_{G(AV)}$	Average Gate Power Dissipation( $T_j=150^{\circ}C$ )			1	W
$P_{GM}$	Peak Gate Power Dissipation( $t_p=20\mu s, T_j=150^{\circ}C$ )			10	W
$T_j$	Operating Junction Temperature			- 40 ~ 150	$^{\circ}C$
$T_{STG}$	Storage Temperature			- 40 ~ 150	$^{\circ}C$



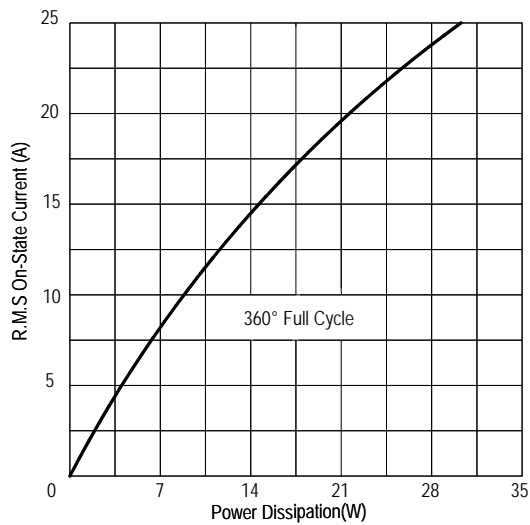
### Electrical Characteristics( $T_j = 25^\circ\text{C}$ unless otherwise specified )

Symbol	Items	Conditions		ADT25CH60F/80F			Unit
				S	Blank	B	
$I_{\text{DRM}}$	Peak Forward Reverse Blocking Current	$V_{\text{DRM}} = V_{\text{RRM}}, T_j = 25^\circ\text{C}$	Max.	5			$\mu\text{A}$
$I_{\text{RRM}}$		$V_{\text{DRM}} = V_{\text{RRM}}, T_j = 150^\circ\text{C}$		8.6			mA
$V_{\text{TM}}$	Peak On-State Voltage	$I_{\text{TM}} = 35\text{A}, t_p = 380 \mu\text{s}$	Max.	1.5			V
$V_{\text{GD}}$	Q1-Q2-Q3	Non-Trigger Gate Voltage $V_D = V_{\text{DRM}}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150^\circ\text{C}$	Min.	0.2			V
$V_{\text{GT}}$	Q1-Q2-Q3	Gate Trigger Voltage $V_D = 12\text{V}, R_L = 33\Omega$	Max.	1.3			V
$I_{\text{GT}}$	Q1-Q2-Q3	Gate Trigger Current	Max.	10	35	50	mA
$I_{\text{H}}$	Q1-Q2-Q3	Holding Current $I_T = 0.1\text{A}$	Max.	20	50	75	mA
$I_{\text{L}}$	Q1-Q3	Latching Current $I_G = 1.2 I_{\text{GT}}$	Max.	20	80	90	mA
	Q2			35	90	110	
$dV/dt$	Critical Rate of Rise of Off-State Voltage	$V_D = 2/3 V_{\text{DRM}}$ gate open $T_j = 150^\circ\text{C}$	Min.	500	1000	1500	$\text{V}/\mu\text{s}$
$(dV/dt)_c$	Critical Rate of Change of Commutating Voltage	$V_D = 400\text{V}, T_j = 150^\circ\text{C}$ $(dI/dt)_c = -12\text{A/ms}$	Min.	1	15	20	$\text{V}/\mu\text{s}$
$R_{\text{th(j-c)}}$	Junction to case (AC)		Max.	1.7			$^\circ\text{C}/\text{W}$
$R_{\text{th(j-a)}}$	Junction to ambient		Max.	60			$^\circ\text{C}/\text{W}$

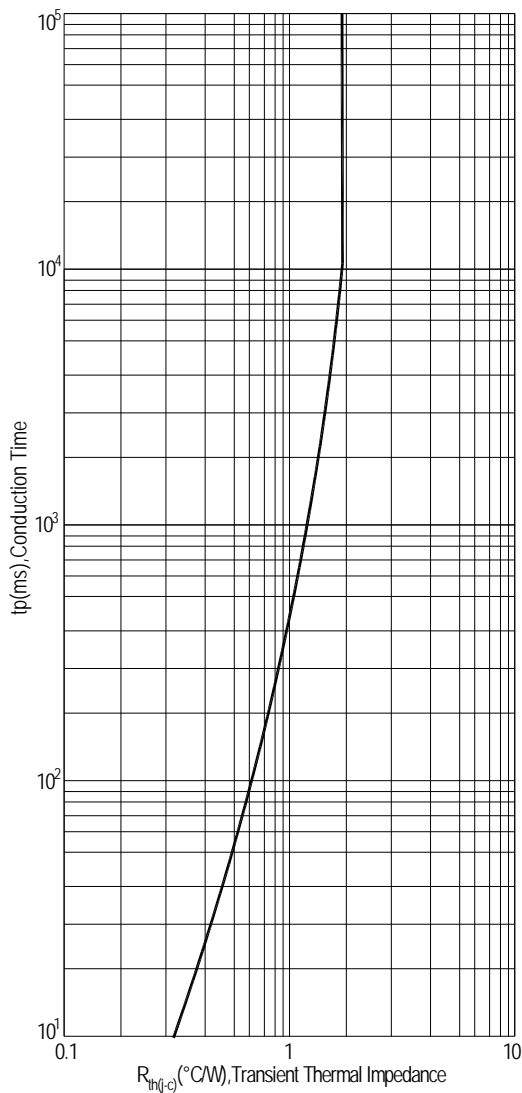
FIG.1: Triac quadrant are defined and the gate trigger test circuit



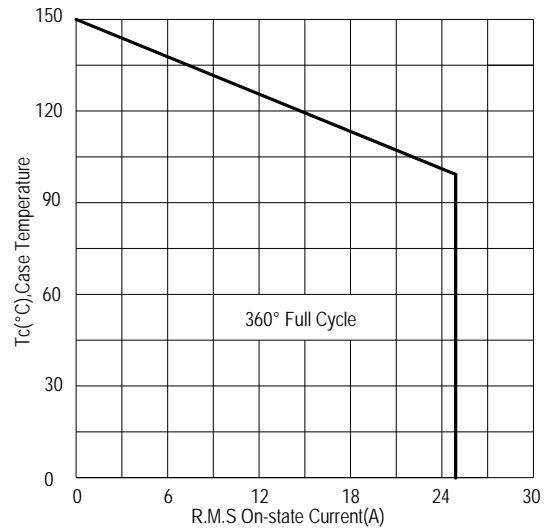
**FIG.2: Maximum on-state power dissipation**



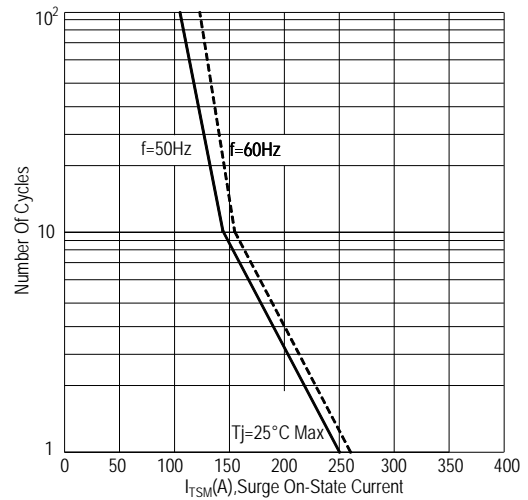
**FIG.4: Maximum transient thermal impedance**



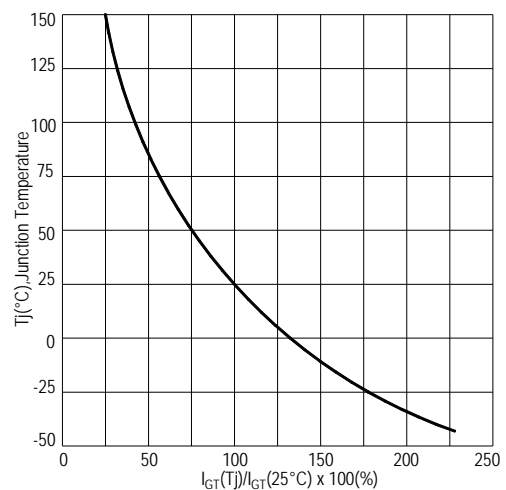
**FIG.3: Typical RMS on-state current VS Allowable case Temperature**



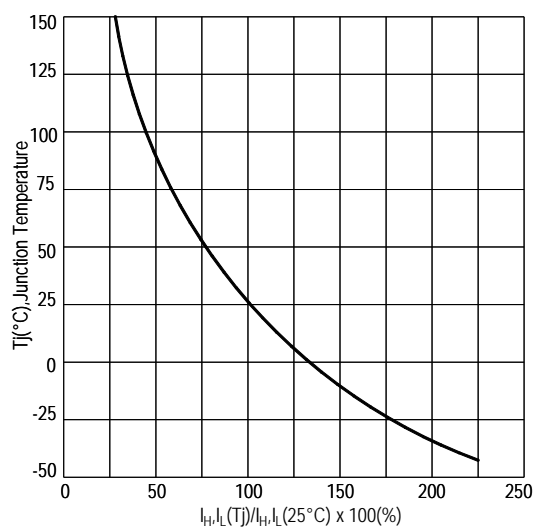
**FIG.5: Rated surge on-state current ( Non-Repetitive)**



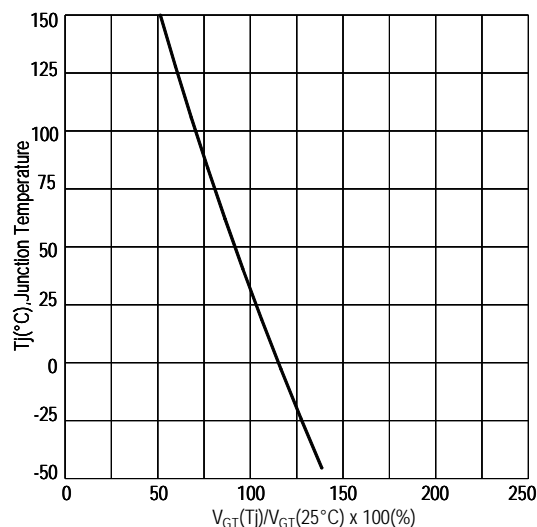
**FIG.6: Gate trigger current VS Junction temperature**



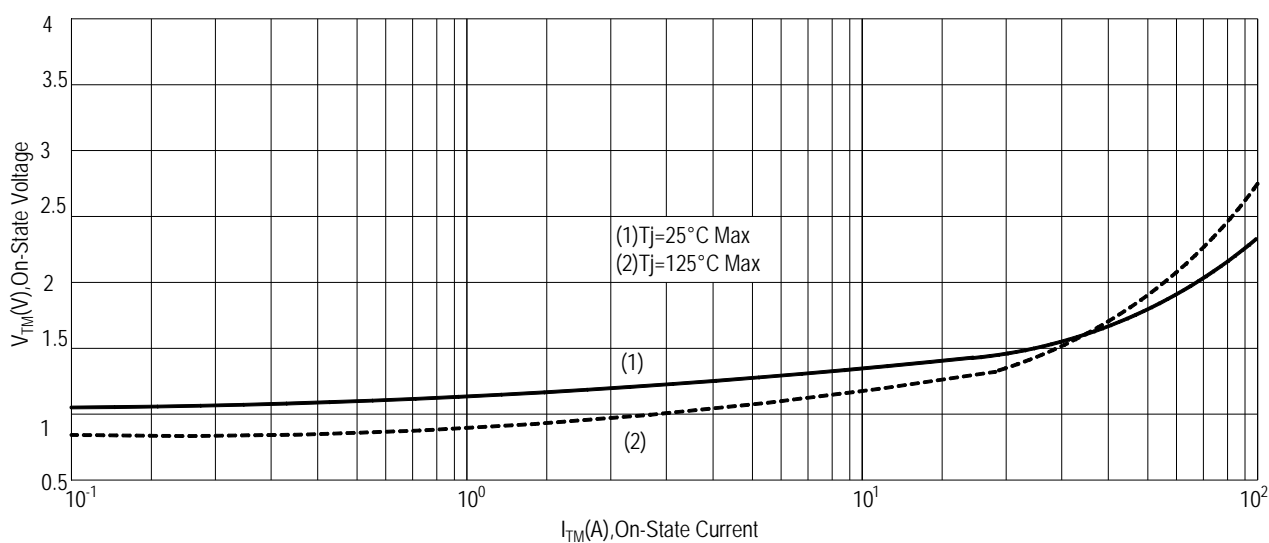
**FIG.7: Holding current and Latching current VS Junction temperature**



**FIG.8: Gate trigger voltage VS Junction temperature**

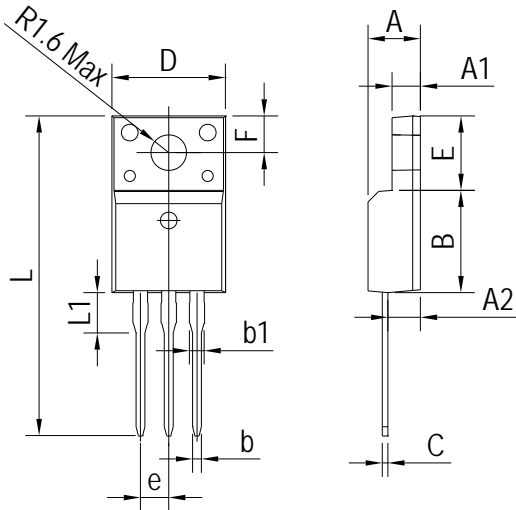


**FIG.9: On-state characteristics(Max)**



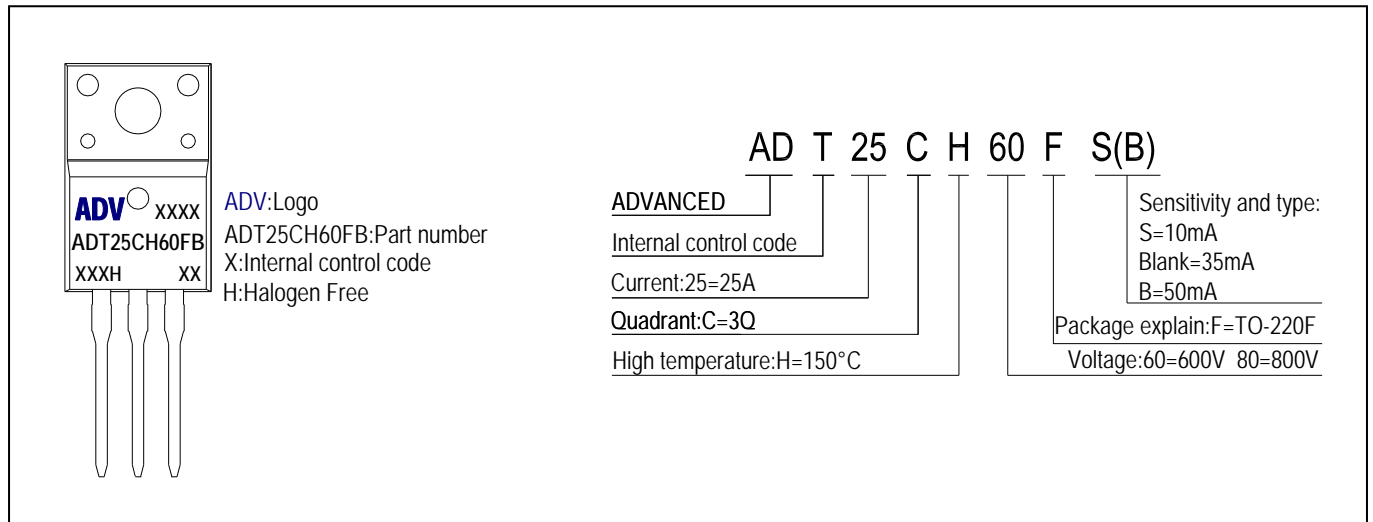
### PACKAGE MECHANICAL DATA

#### TO-220F Package Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.300	4.800	0.169	0.189
A1	2.400	2.700	0.094	0.106
A2	2.500	3.000	0.098	0.118
B	8.800	9.300	0.346	0.367
b	0.600	0.950	0.023	0.037
b1	1.100	1.700	0.043	0.067
C	0.500	0.750	0.020	0.030
D	9.700	10.360	0.382	0.408
E	6.400	6.800	0.252	0.268
e	2.540 TYP		0.100 TYP	
F	3.300 REF		0.130 REF	
L	28.000	30.000	1.102	1.181
L1	2.900	3.630	0.114	0.143

### Making Diagram



### Ordering information

Part number	Package	Marking	Packing	Quantity
ADT25CH60F#	TO-220F	ADT25CH60F#	Tube	50pcs
ADT25CH80F#	TO-220F	ADT25CH80F#	Tube	50pcs

Note: # = Gate Trigger Current Sensitivity and type

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